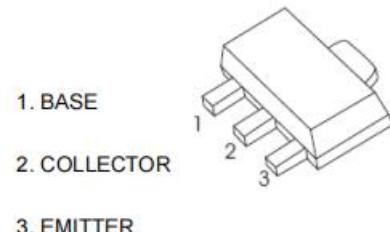


**SOT-89-3L Bipolar Transistor 双极型三极管****■Features 特点**

NPN High Voltage 高压

**■Absolute Maximum Ratings 最大额定值**

Characteristic 特性参数	Symbol 符号	Rating 额定值	Unit 单位
Collector-Base Voltage 集电极基极电压	V <sub>CBO</sub>	250	V
Collector-Emitter Voltage 集电极发射极电压	V <sub>CEO</sub>	250	V
Emitter-Base Voltage 发射极基极电压	V <sub>EBO</sub>	5	V
Collector Current 集电极电流	I <sub>C</sub>	50	mA
Power dissipation 耗散功率	P <sub>C</sub> (T <sub>a</sub> =25°C)	500	mW
Thermal Resistance Junction-Ambient 热阻	R <sub>θJA</sub>	250	°C/W
Junction and Storage Temperature 结温和储藏温度	T <sub>J</sub> , T <sub>stg</sub>	-55 to +150	°C

**■Device Marking 产品打标**

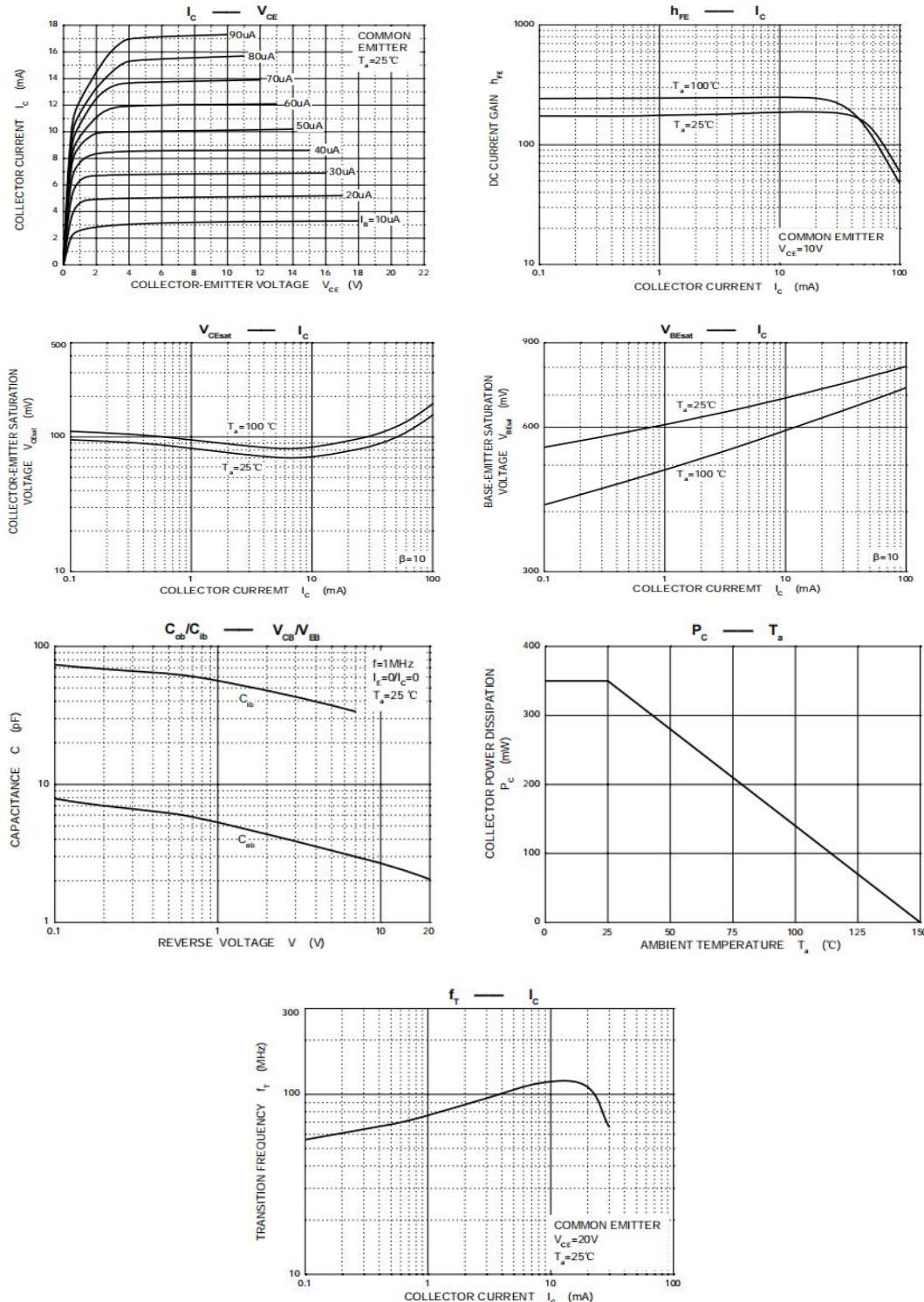
BF622=DA

**■ Electrical Characteristics 电特性**

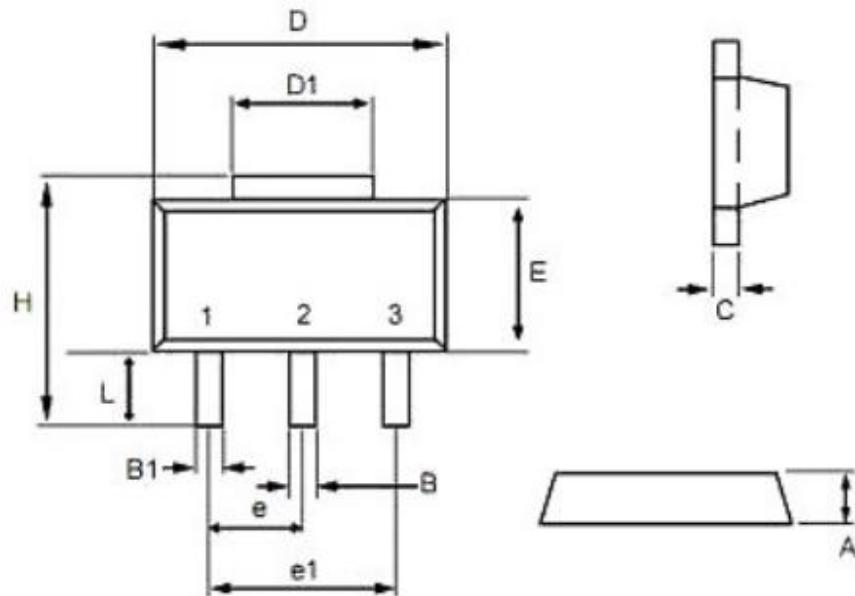
(TA=25°C unless otherwise noted 如无特殊说明, 温度为 25°C)

Characteristic 特性参数	Symbol 符号	Min 最小值	Type 典型值	Max 最大值	Unit 单位
Collector-Base Breakdown Voltage 集电极基极击穿电压( $I_C = 100\mu A$ , $I_E = 0$ )	$BV_{CBO}$	250	—	—	V
Collector-Emitter Breakdown Voltage 集电极发射极击穿电压( $I_C = 1mA$ , $I_B = 0$ )	$BV_{CEO}$	250	—	—	V
Emitter-Base Breakdown Voltage 发射极基极击穿电压( $I_E = 100\mu A$ , $I_C = 0$ )	$BV_{EBO}$	5	—	—	V
Collector-Base Leakage Current 集电极基极漏电流( $V_{CB} = 200V$ , $I_E = 0$ )	$I_{CBO}$	—	—	100	nA
Collector-Emitter Leakage Current 集电极发射极漏电流( $V_{CE} = 200V$ , $I_B = 0$ )	$I_{CEO}$	—	—	100	nA
Emitter-Base Leakage Current 发射极基极漏电流( $V_{EB} = 5V$ , $I_C = 0$ )	$I_{EBO}$	—	—	100	nA
DC Current Gain 直流电流增益( $V_{CE} = 20V$ , $I_C = 1mA$ )	$H_{FE}(1)$	60	—	—	
DC Current Gain 直流电流增益( $V_{CE} = 20V$ , $I_C = 10mA$ )	$H_{FE}(2)$	100	—	200	
DC Current Gain 直流电流增益( $V_{CE} = 20V$ , $I_C = 25mA$ )	$H_{FE}(3)$	50	—	—	
Collector-Emitter Saturation Voltage 集电极发射极饱和压降( $I_C = 20mA$ , $I_B = 2mA$ ) ( $I_C = 30mA$ , $I_B = 5mA$ )	$V_{CE(sat)}$	—	—	200 600	mV
Base-Emitter Saturation Voltage 基极发射极饱和压降( $I_C = 20mA$ , $I_B = 2mA$ )	$V_{BE(sat)}$	—	—	900	mV
Transition Frequency 特征频率( $V_{CE} = 10V$ , $I_C = 10mA$ )	$f_T$	60	—	—	MHz
Output Capacitance 输出电容( $V_{CB} = 20V$ , $I_E = 0$ , $f = 1MHz$ )	$C_{ob}$	—	6	—	pF

■Typical Characteristic Curve 典型特性曲线



## ■ Dimension 外形封装尺寸



Symbol	Dimensions In Millimeters		Dimensions In Inches	
	Min	Max	Min	Max
A	1.40	1.60	0.055	0.063
B	0.40	0.56	0.016	0.022
B1	0.35	0.48	0.014	0.019
C	0.35	0.44	0.014	0.017
D	4.40	4.60	0.173	0.181
D1	1.35	1.83	0.053	0.072
e	1.45	1.55	0.057	0.061
e1	2.95	3.05	0.116	0.120
E	2.29	2.60	0.090	0.102
H	3.75	4.25	0.148	0.167
L	0.80	1.20	0.031	0.047